

# Quantum Computing with neutral atoms and artificial ions

NIST, Gaithersburg:

Carl Williams

Paul Julienne

T. C.



Quantum Optics Group, Innsbruck:

Peter Zoller

Andrew Daley

Uwe Dörner

Peter Fedichev

Peter Rabl



# Outline

- [Quantum Computing based on] neutral atoms in optical lattices
  - spin-dependent lattices
  - high fidelity loading of large lattice arrays beyond Mott insulator

Rabl et al.

- Entangling atoms
  - two-atoms Feshbach & photoassociation gates
  - atoms in pipeline structures

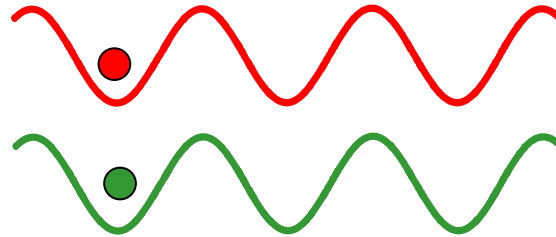
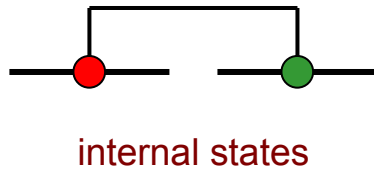
Dorner et al.

experiments by  
I. Bloch et al., LMU  
& NIST Gaithersburg

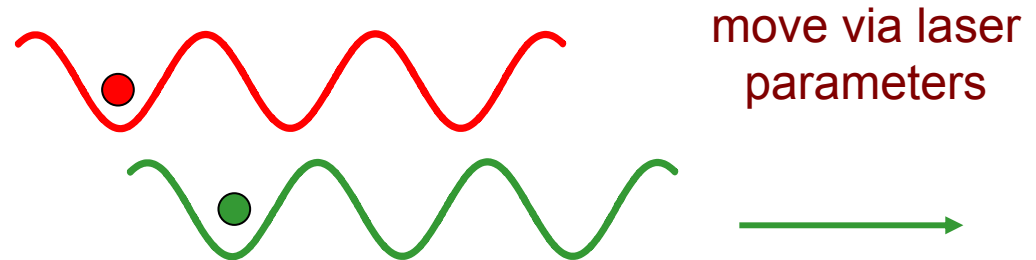
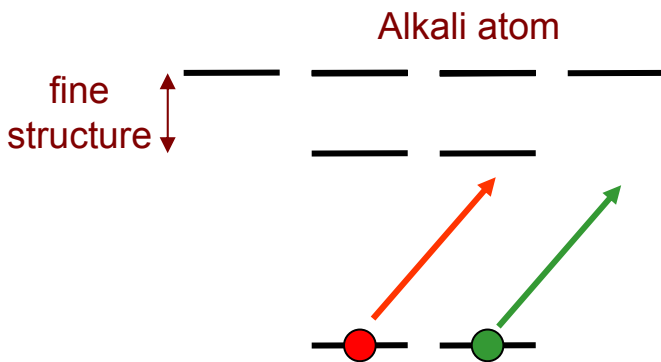
- All-optical quantum computing with quantum dots
  - Suppressing decoherence via quantum-optical techniques

# Background: atoms in spin-dependent optical lattices

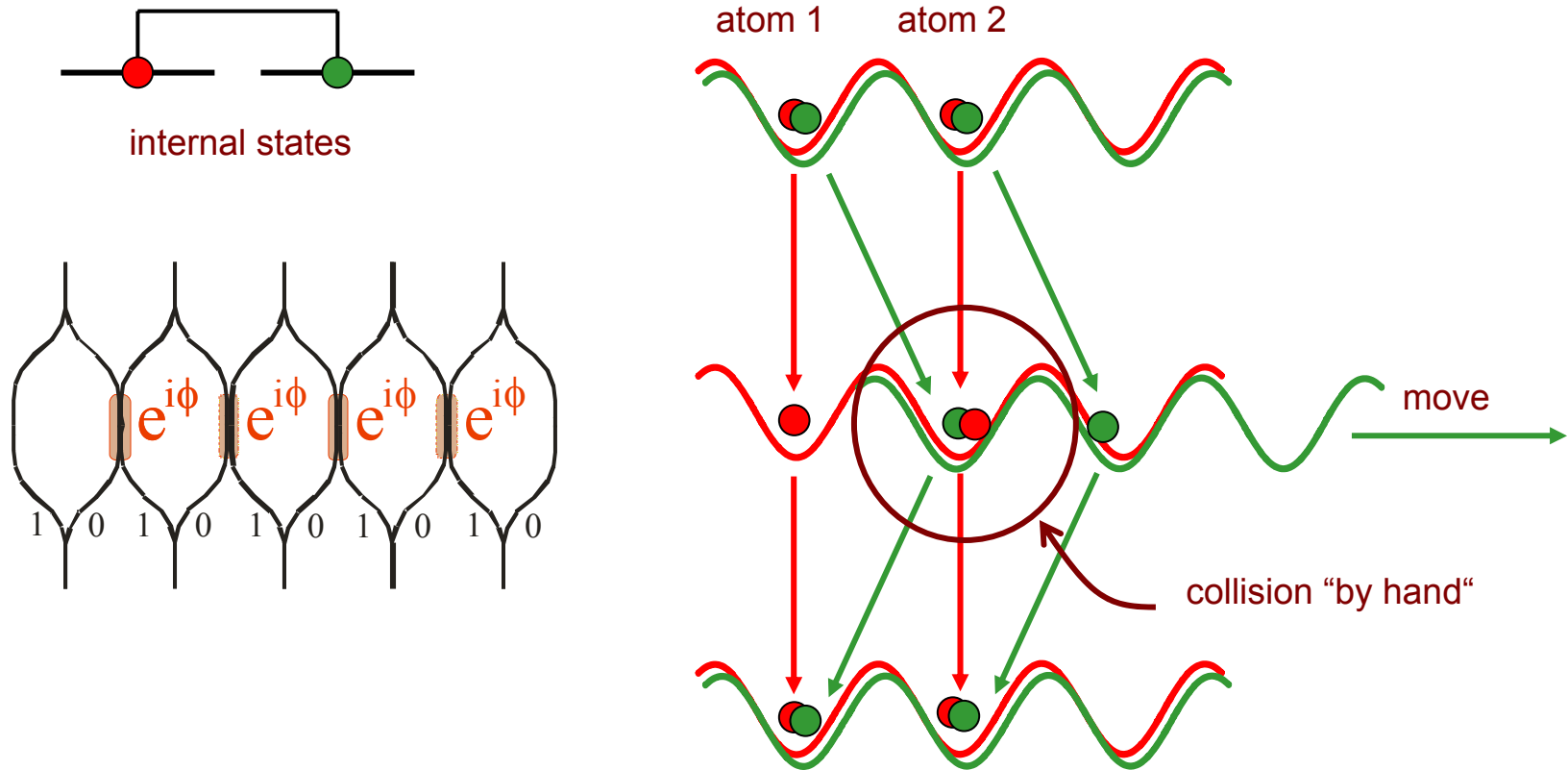
- optical lattice: spatially varying AC Stark shifts by interfering laser beams
- trapping potential depends on the internal state



- we can move one potential relative to the other, and thus transport the component in one internal state



- interactions by moving the lattice + colliding the atoms “by hand”



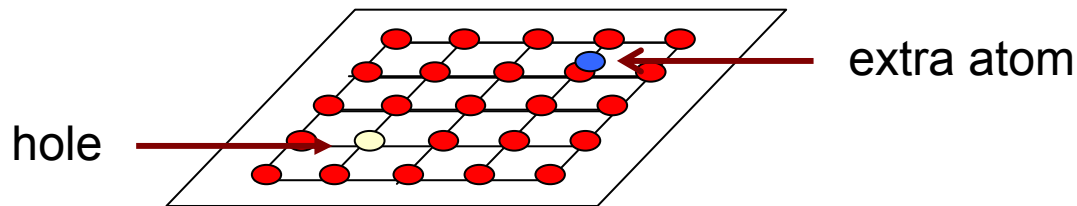
- Ising type interaction: building block of the Universal Quantum Simulator

$$H = \frac{J}{2} \sum_{a,b} \sigma_a^z \sigma_b^z$$

nearest neighbor, next to nearest neighbor ....

# Correcting defects in optical lattices

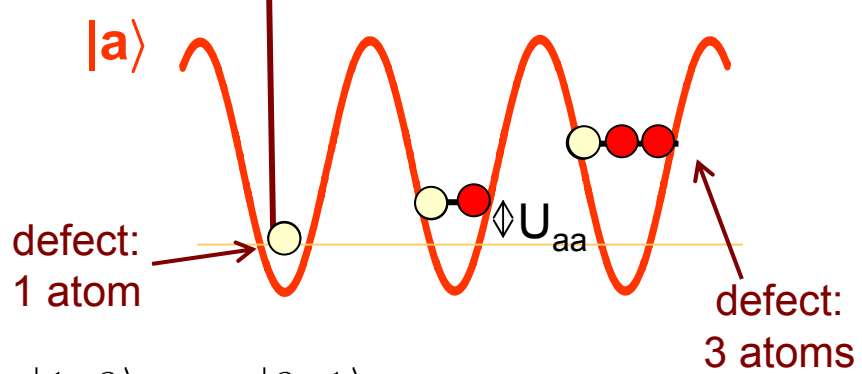
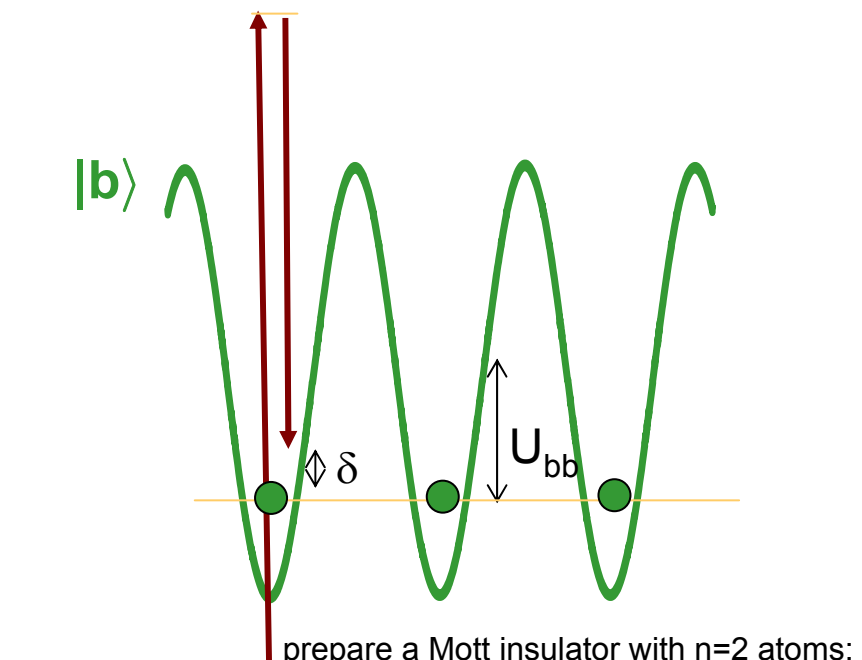
- Preparation of qubits via a superfluid – Mott insulator phase transition
- Mott insulator have still some defects ...  
present LMU exp.: approx. 1 out of 10 (not optimized)



- Questions:
  - ✓ Even “more regular” loading?
  - ✓ Can we heal defects?
  - ✓ Self-healing?

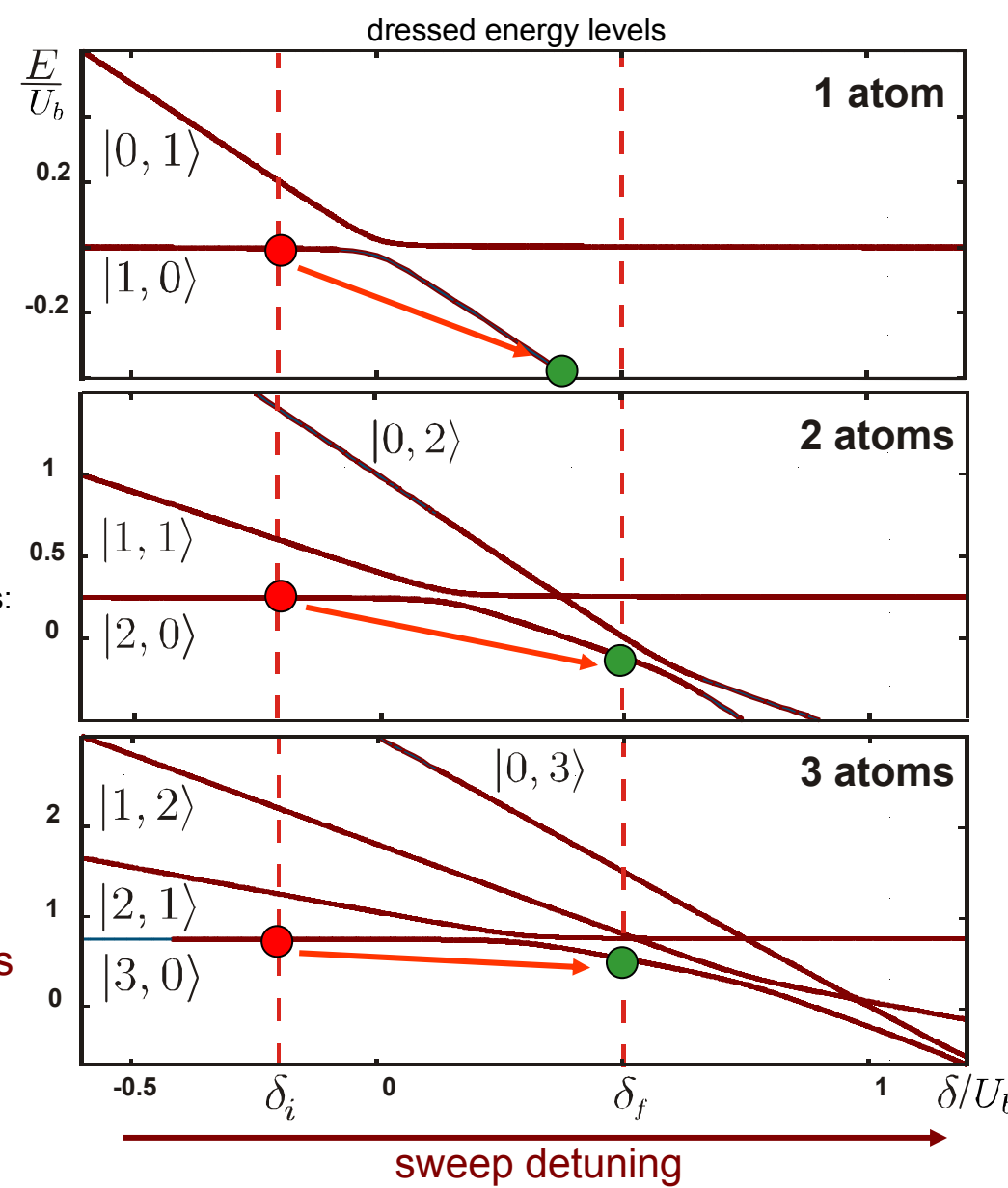
Rem: it seems difficult to do this in normal solids

# Defect free optical crystals (for quantum computing)



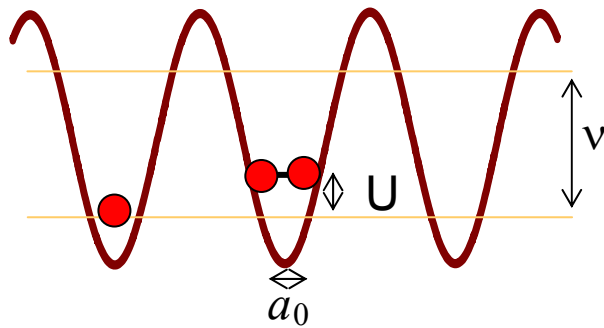
- $|1, 0\rangle \longrightarrow |0, 1\rangle$
- $|2, 0\rangle \longrightarrow |1, 1\rangle$
- $|3, 0\rangle \longrightarrow |2, 1\rangle$

After detuning sweep:  
exactly one atom in b



# Collision gates & speed

- validity of the Hubbard model

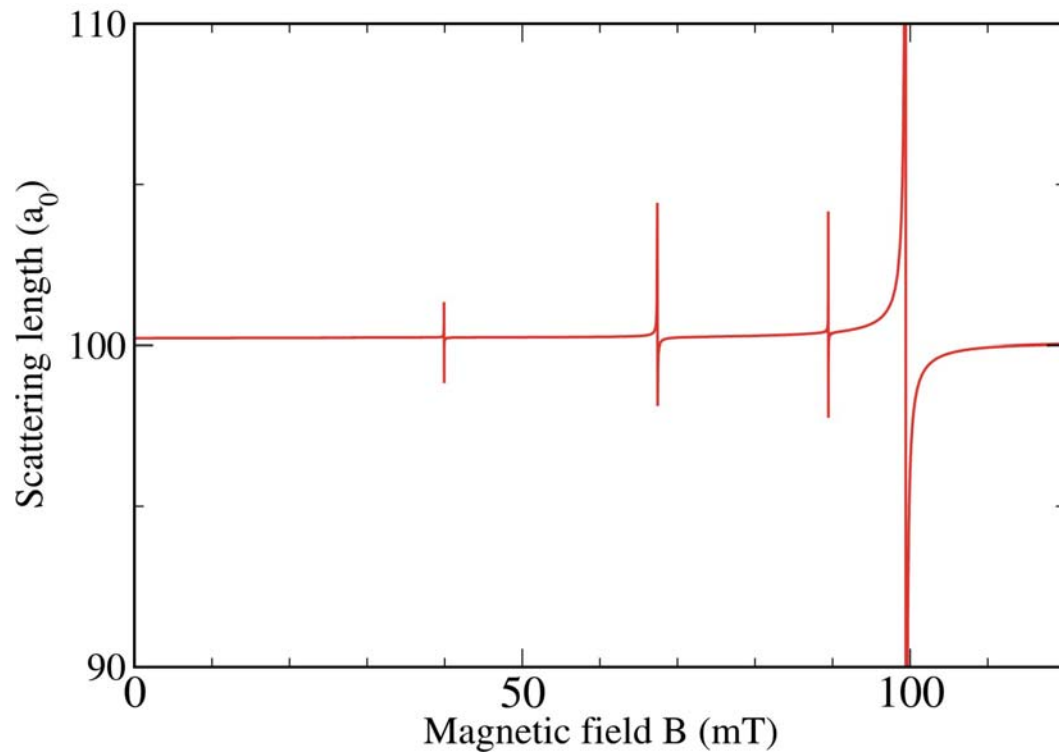


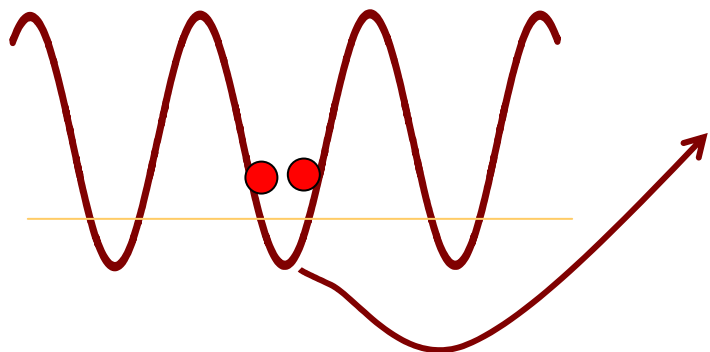
$$U = \frac{4 a_s^2}{m} \int d^3x |w(x)|^4$$

↑ scattering length  $a_s$ 
 $a_0$

- we can tune to a resonance to have a (free space) scattering length

<sup>87</sup>Rb scattering length ( $E/k_B=1$  nK) for a + a collisions



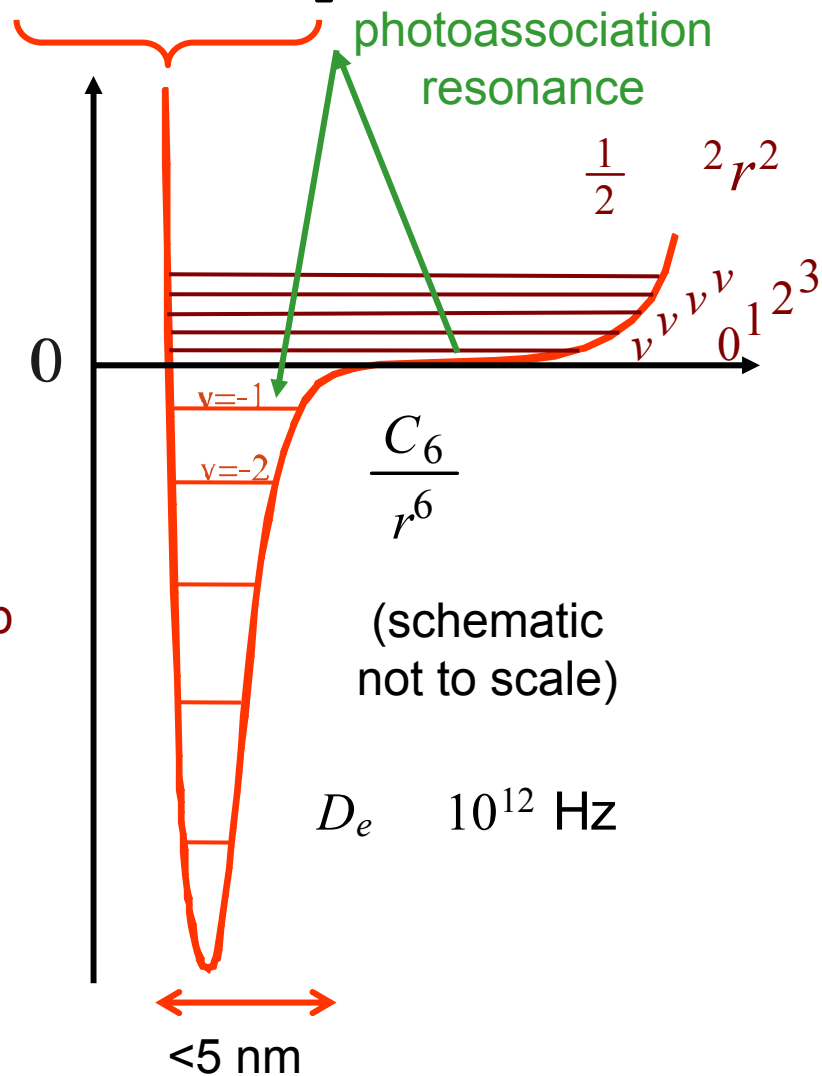


harmonic approximation

$$\left[ \frac{\hbar^2}{2m} \frac{\partial^2}{\partial R^2} + \frac{1}{2} 2m \omega^2 R^2 \right] \psi_{cm} = E_{cm} \psi_{cm}$$

$$\left[ \frac{\hbar^2}{2m} \frac{\partial^2}{\partial r^2} + V(r) \right] \psi_r = E \psi_r$$

Born Oppenheimer potentials including trap





# Coupling into molecular states via a “Feshbach ramp”

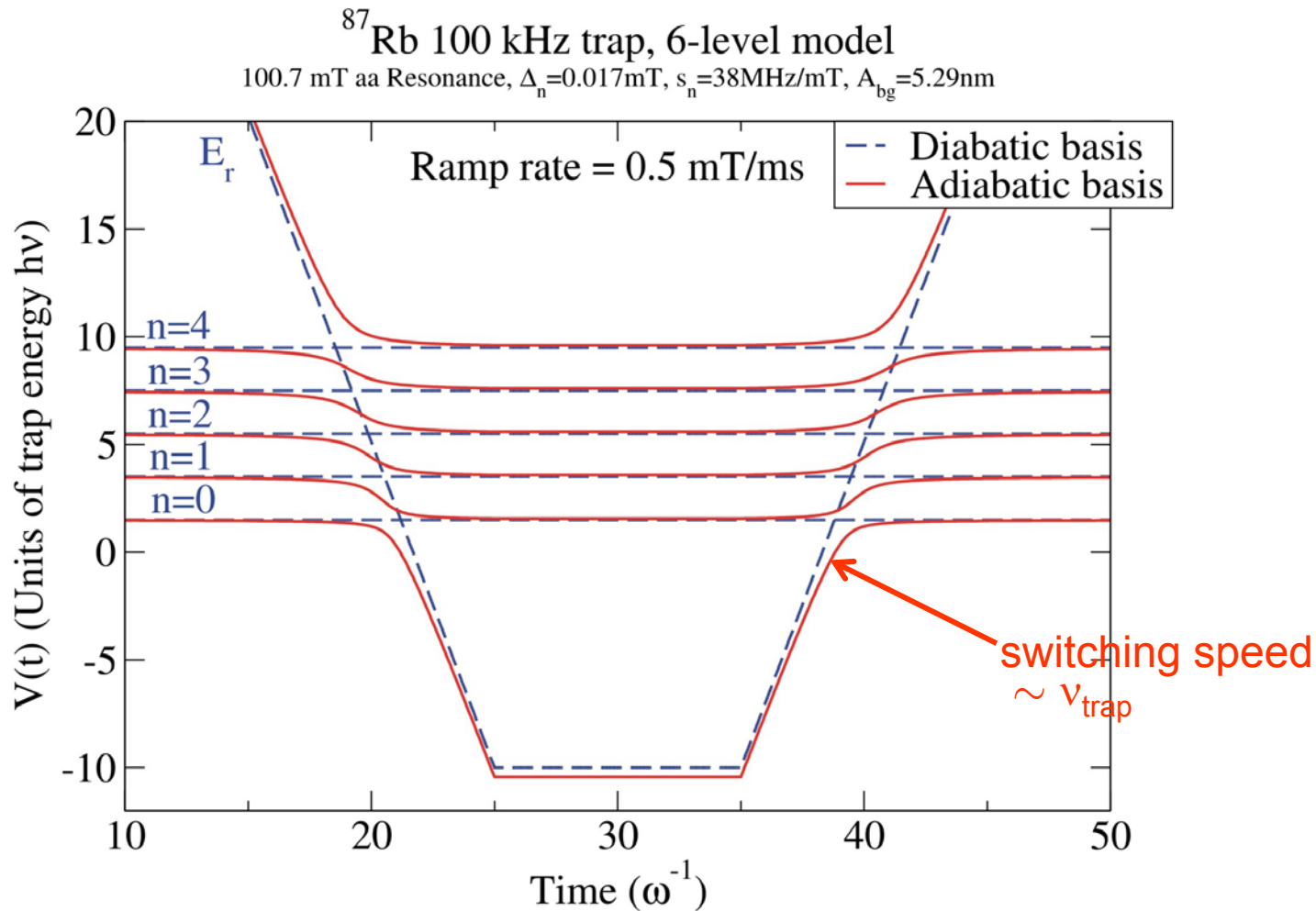
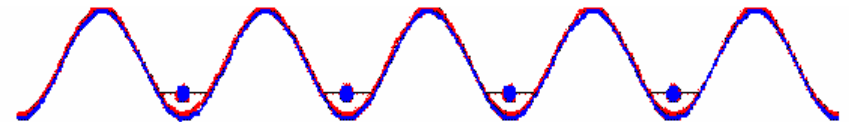
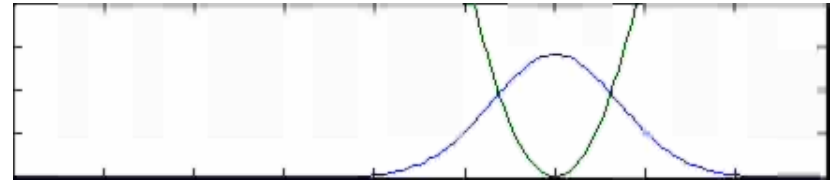
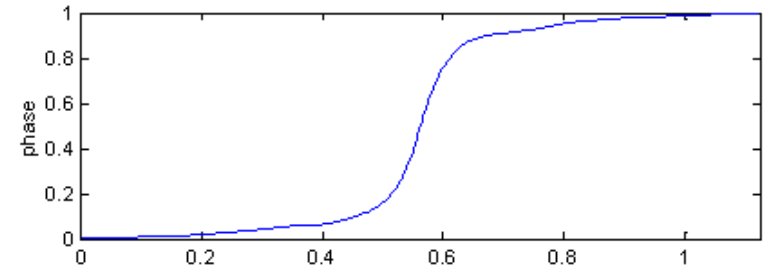
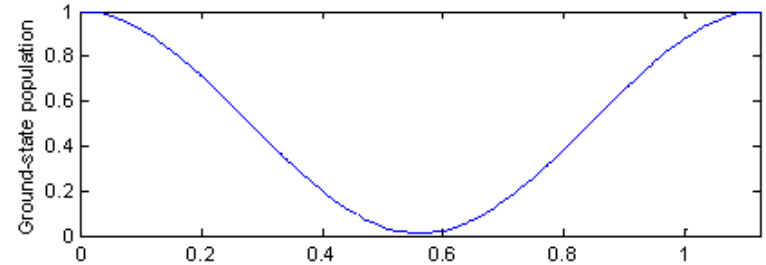


FIG. 7. Diabatic and adiabatic energy levels of a double Feshbach ramp. The bare resonance energy is held at a constant value between times  $t\omega_h$  of 25 and 35, then ramped back across threshold with a ramp functions that is the inverse of the first one.

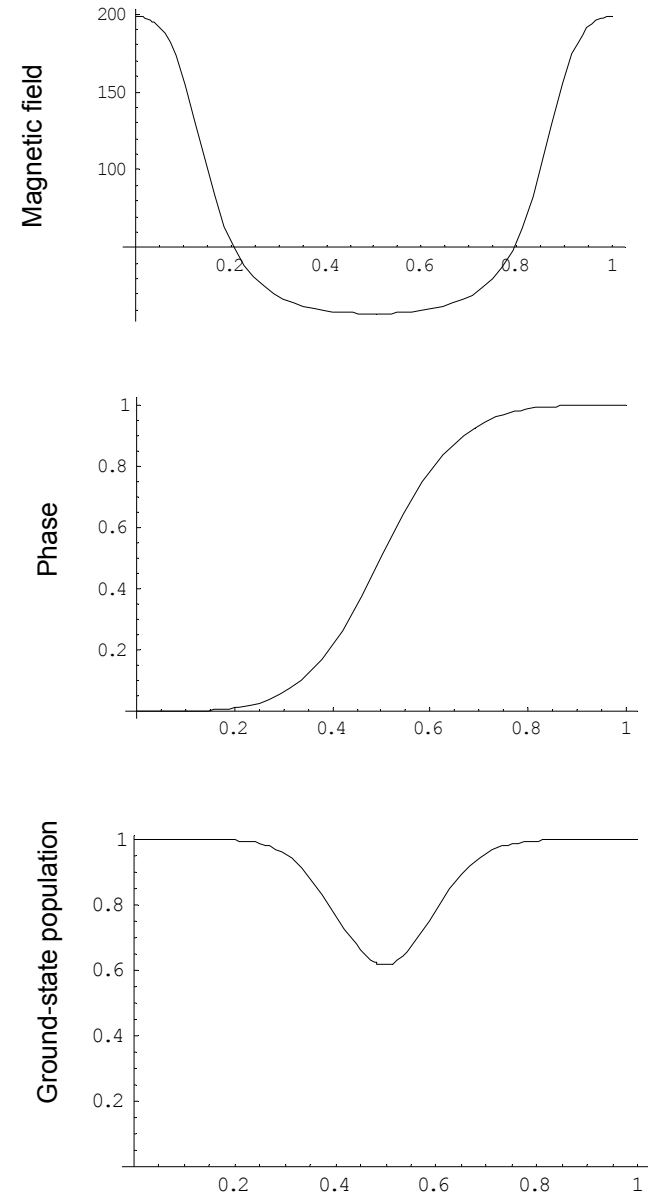
# Feshbach switching in a spherical trap

- Start with the Feshbach resonance state 10 trap units above threshold
- Switch it suddenly close to threshold
- Wait  $\sim 1$  trap time ( $\sim \mu\text{s}$  assuming MHz trap)
- Switch back
- A phase  $\pi$  is accumulated
- Fidelity: 0.9996
- No state dependence required, however difficult atom separation with state-independent potential
- State dependence: lattice displacement
- Non-adiabatic transport in optical lattice: simulation with realistic potential shape
- Fidelity 0.99999 in 1.5 trap times through optimal control theory



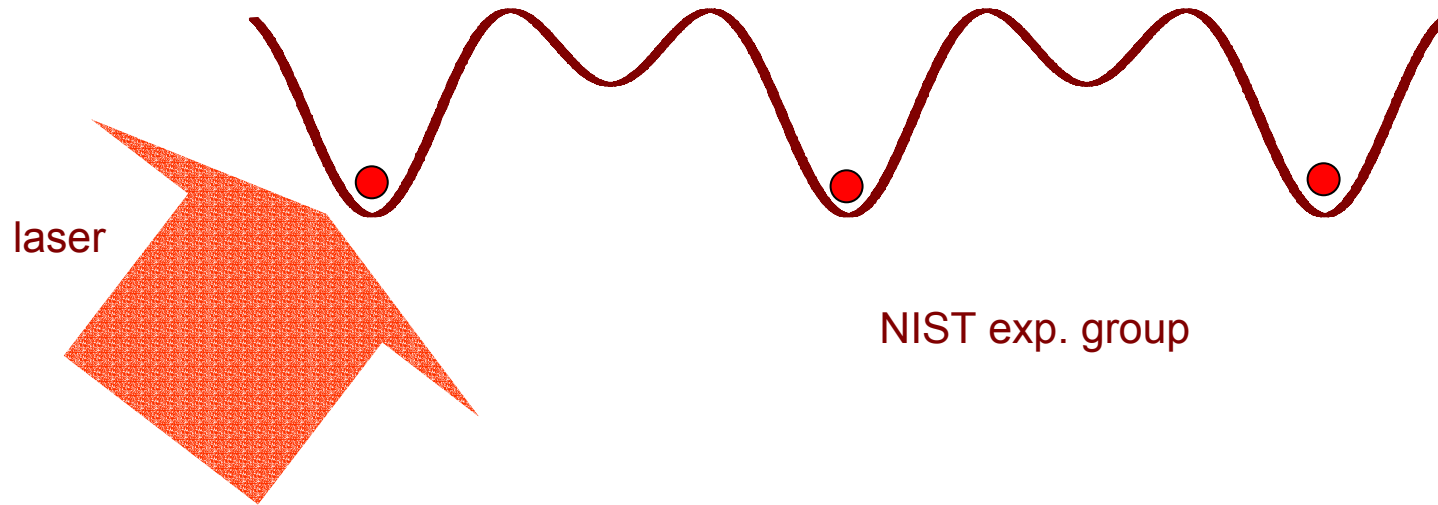
# Feshbach ramp in an elongated trap

- Assumptions:
  - Cigar-shaped trap
  - Transverse motion “frozen”
- Lower longitudinal density of states
  - Bigger coupling to each level
  - Smaller non-adiabatic crossing
- Smoothly varying magnetic field
- Phase gate in 1 trap time with fidelity 0.9996
- Disadvantage: quasi-1D requirement limits trap frequency & speed
- Idea: use this in a “free-fall” scheme where no state-dependent potential would be needed

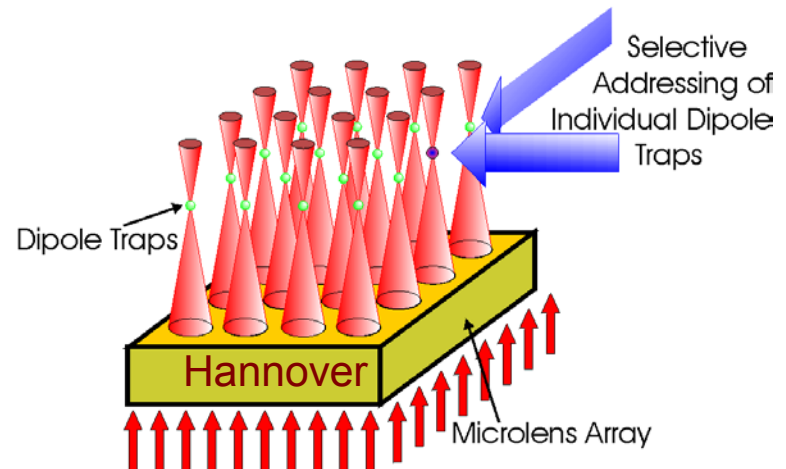


# Alternative trap designs

- pattern loading, e.g for addressing single atoms

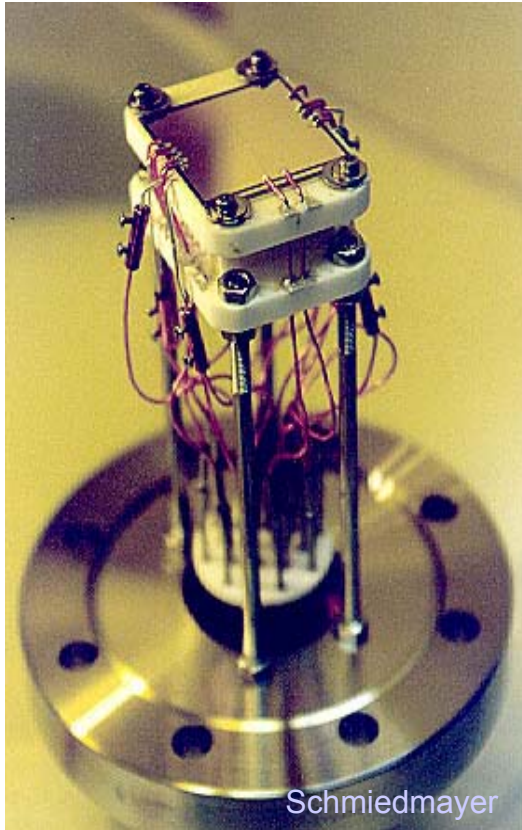


- Microlens arrays



# Atom chips

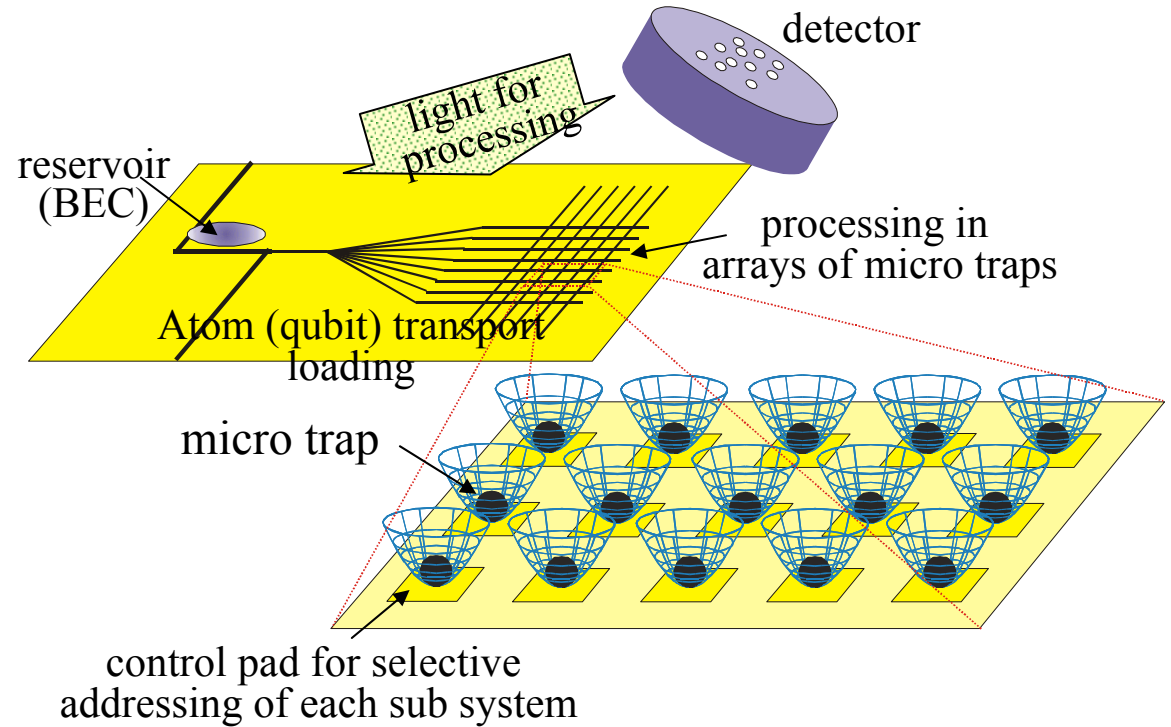
- magnetic traps



Heidelberg, Munich,  
Harvard, Orsay

issues:

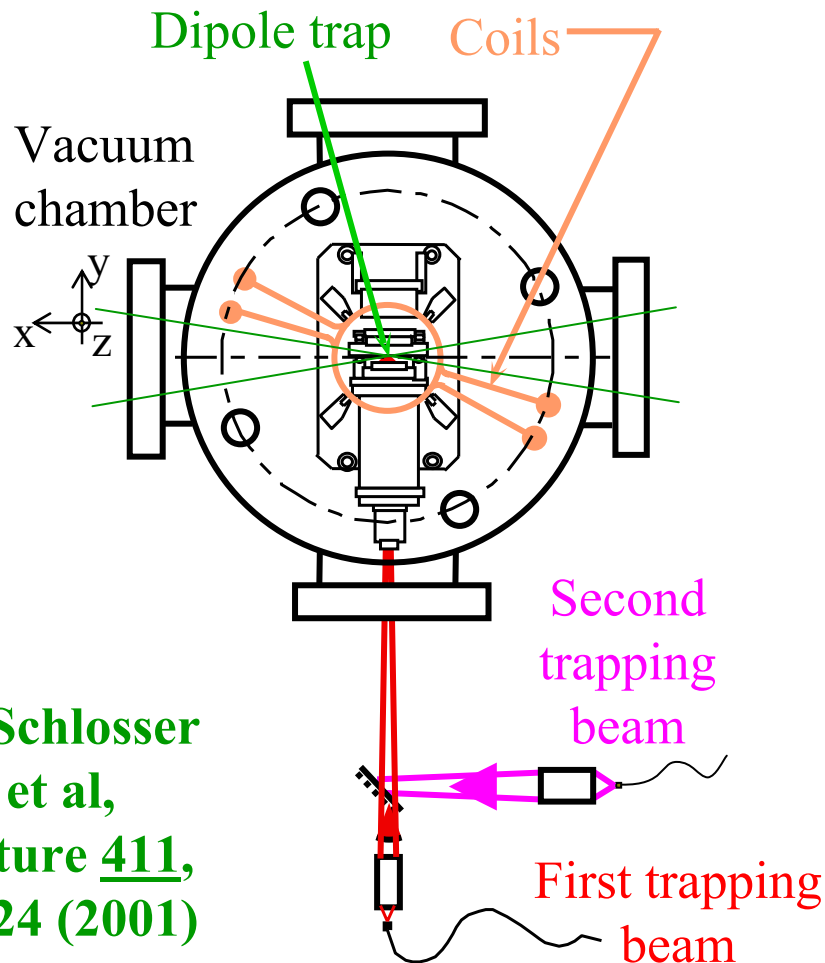
- ✓ conservative potential
- ✓ surface effects
- ✓ single atom loading
- ✓ laser cooling
- ✓ loading from a BEC
- linear ion trap
- Mott insulator loading?



# Optical-tweezers double trap for two single atoms

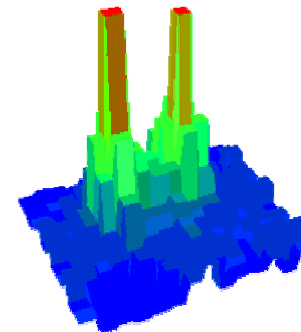
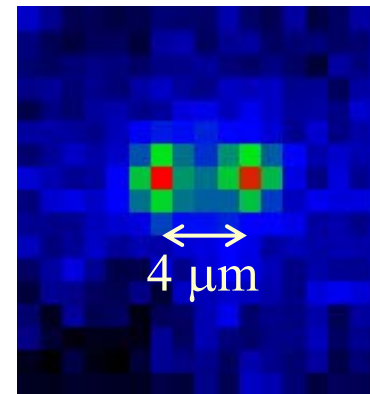
© Grangier

- A single atom is trapped in each site



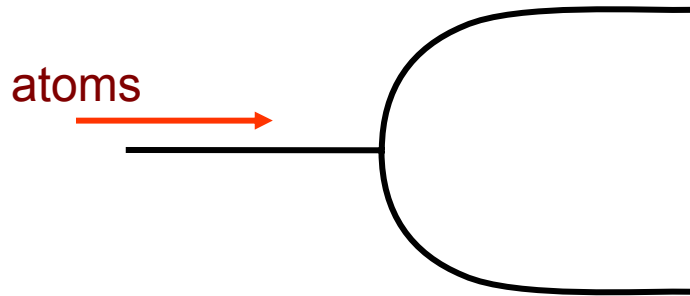
N. Schlosser  
et al,  
Nature 411,  
1024 (2001)

Resolution of the imaging  
system: **one micron per pixel**

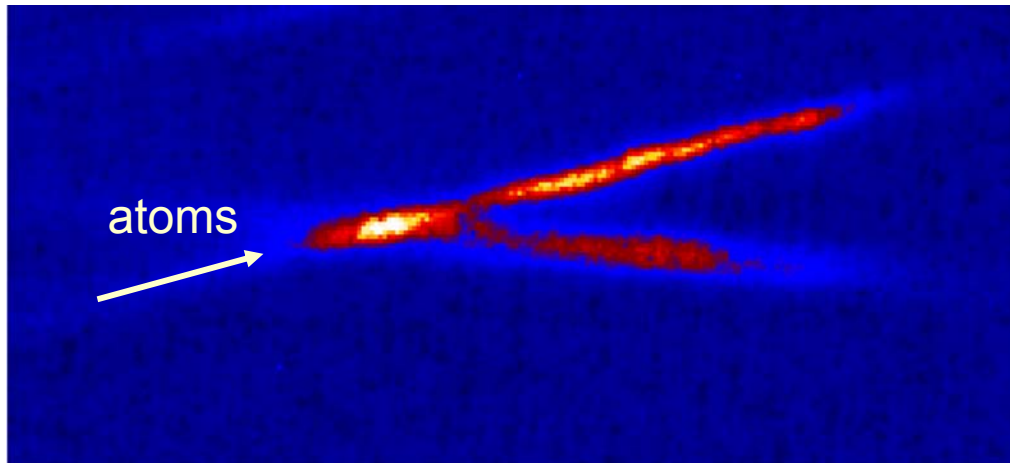


# Atoms in 1D pipelines

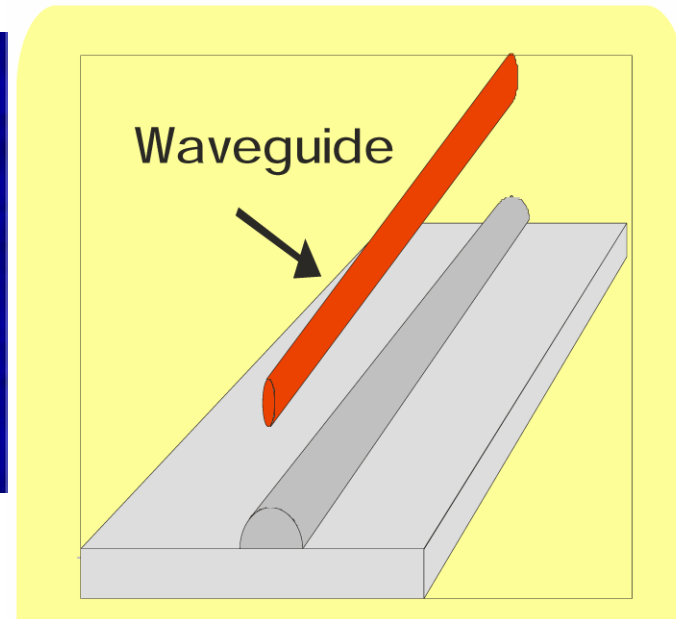
- beamsplitter



- motivation: 1D experiments with optical (and magnetic) traps



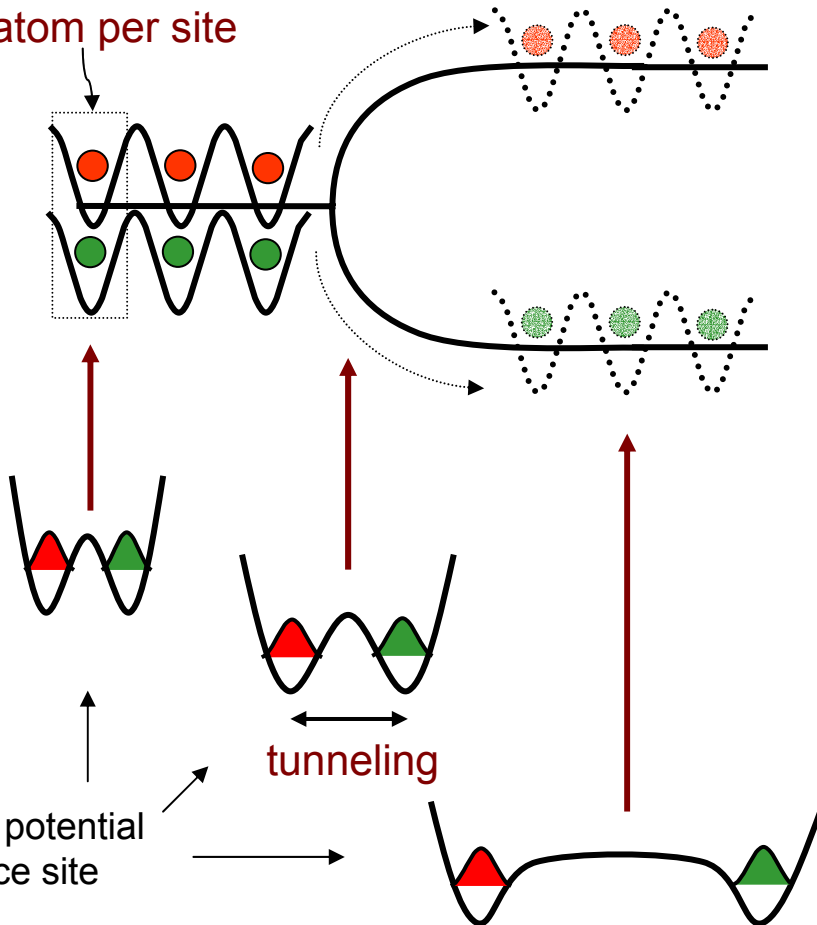
beam splitter (Hannover)



# Atoms in 1D lattices

Beam splitter

1 atom per site



atoms in a longitudinal lattice are moved across a beam splitter

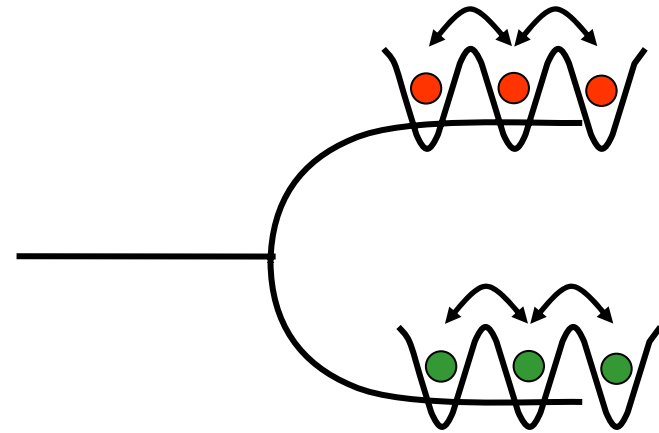
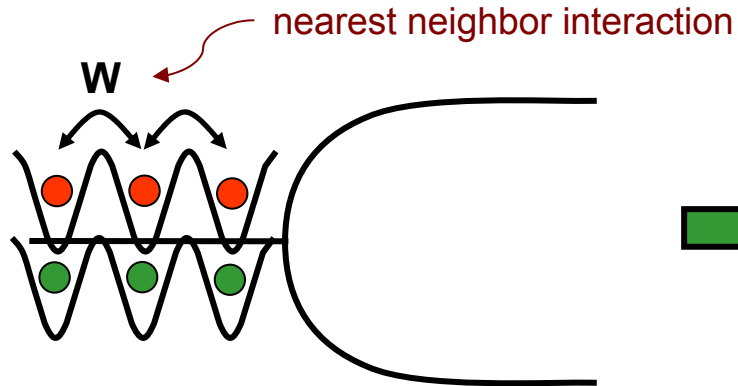
splitter increases "spatial separation" of the wells in an adiabatic way

transverse potential at a lattice site



# Atoms in 1D lattices

Beam splitter: attractive or repulsive interaction between adjacent atoms



$$(\alpha|\bullet\rangle + \beta|\circ\rangle)^{\otimes N}$$

product state

attractive

$$\alpha|\circ\circ\circ\rangle + \beta|\bullet\bullet\bullet\rangle$$

max entangled state

repulsive

$$\alpha|\circ\bullet\circ\rangle + \beta|\bullet\circ\bullet\rangle$$

max entangled state

Nearest neighbor interaction: cold collisions, dipole-dipole (Rydberg atoms)

Jaksch et al. PRL 82, 1975 (1999), Jaksch et al. PRL 85, 2208 (2000)

# Atoms in 1D lattices

## Motivations:

→ Interferometry (attractive interaction)

$$(\alpha|\uparrow\rangle + \beta|\downarrow\rangle)^{\otimes N} \xrightarrow{\quad} \alpha|\bullet\bullet\bullet\bullet\rangle + \beta|\quad\quad\quad\rangle$$

very sensitive to (global) unbalance

$$\xrightarrow{\quad} \alpha|\bullet\bullet\bullet\bullet\rangle + \beta e^{iN\phi}|\uparrow\uparrow\uparrow\uparrow\rangle$$

→ Store qubit in a protected quantum memory (repulsive interaction)

$$\alpha|\uparrow\bullet\uparrow\bullet\rangle + \beta|\uparrow\bullet\bullet\uparrow\rangle$$

unbalance:



insensitive to (global) unbalance

# Quantum Information Processing

Identifying the ground states as qubits:

$$|0\rangle = |\downarrow\uparrow \dots \downarrow\uparrow\rangle$$

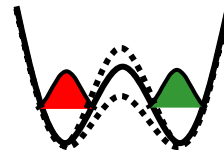
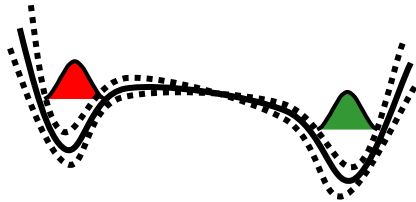
$$|1\rangle = |\uparrow\downarrow \dots \uparrow\downarrow\rangle$$

→  $J_x = 0$ : Two degenerate ground states form a protected quantum memory

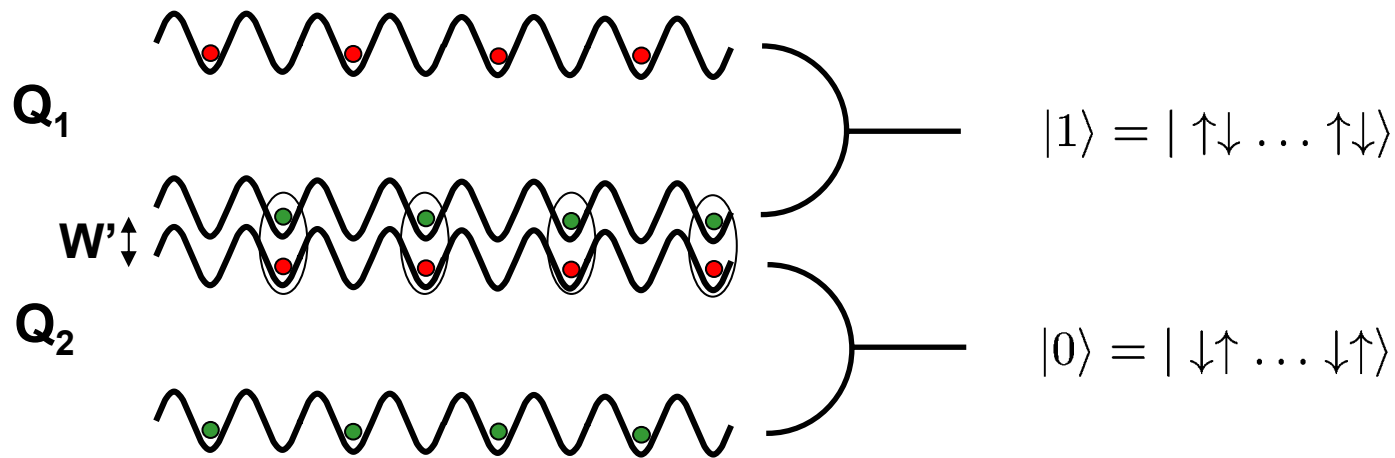
➤ Separated by a gap  $2W$  from the higher excited states

➤ Insensitive to global fluctuations of the form  $\sim \sum_{l=1}^N \sigma_l^{x,y,z}$

(fluctuations in unbalance, fluctuations in tunneling barrier)



# Two qubit gates



➔ Interaction  $W'$  leads to state selective time evolution

**Truth table:**

$$|0\rangle|0\rangle \longrightarrow |0\rangle|0\rangle$$

$$|1\rangle|1\rangle \longrightarrow |1\rangle|1\rangle$$

$$|0\rangle|1\rangle \longrightarrow e^{-i\phi}|0\rangle|1\rangle$$

$$|1\rangle|0\rangle \longrightarrow e^{-i\phi}|1\rangle|0\rangle$$

**Collectively enhanced phase:**

$$\phi = NW'\tau/2$$

# All-optical spin quantum gates in quantum dots

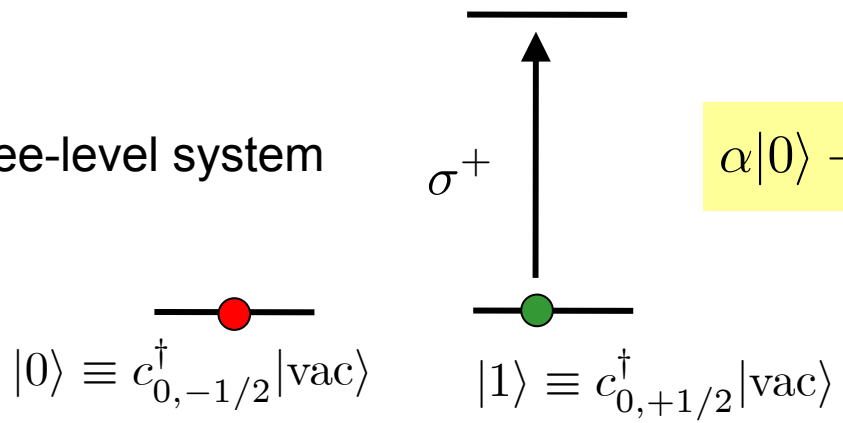
- QIP: solid state implementation
  - + scalable, fast
  - + in line with present nanostructure developments
  - decoherence
- ... coming from quantum optics
  - quantum dots are like artificial atoms: „engineering“ atomic structure
  - spin-based optical quantum gates in semiconductor quantum dots
- ideas from quantum optics may help in suppressing decoherence

# Coupling spin to charge via Pauli blocking



$$|x^-\rangle \equiv c_{0,1/2}^\dagger c_{0,-1/2}^\dagger d_{0,3/2}^\dagger |\text{vac}\rangle$$

Idealized model: three-level system

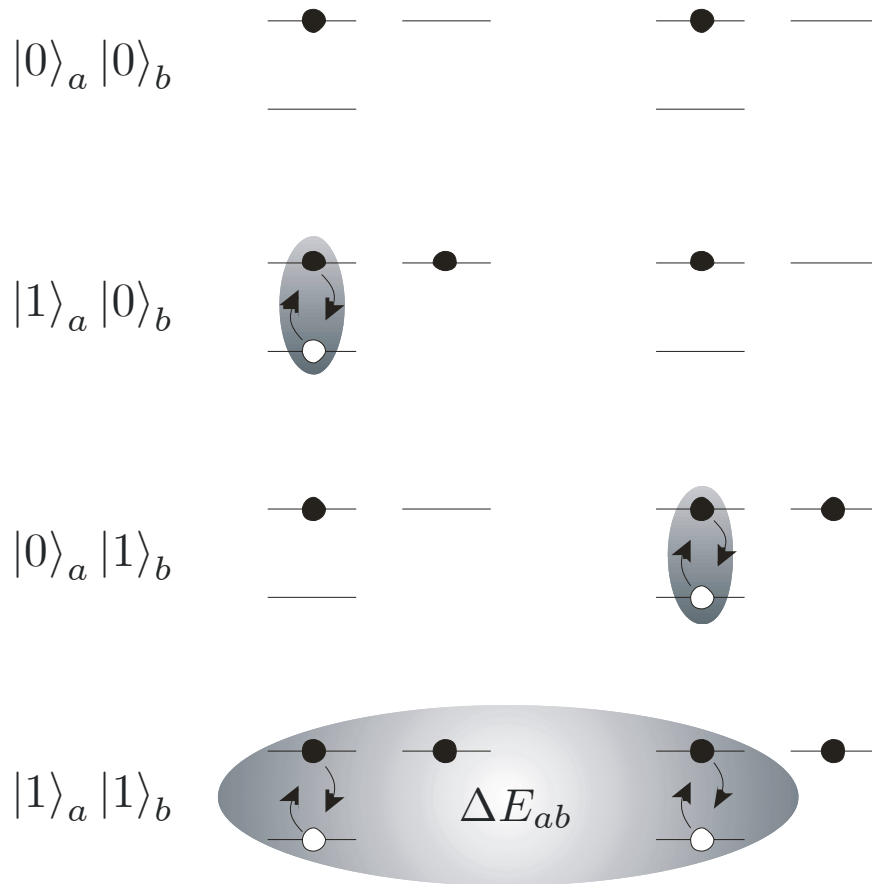


$$|0\rangle \equiv c_{0,-1/2}^\dagger |\text{vac}\rangle$$

$$|1\rangle \equiv c_{0,+1/2}^\dagger |\text{vac}\rangle$$

$$\alpha|0\rangle + \beta|1\rangle \rightarrow \alpha|0\rangle + \beta|x^-\rangle$$

# Selective phase via bi-excitonic interaction



- Laser addressing
- Exciton couples only to state  $|1\rangle$
- External electric field displaces electrons and holes
- Dipole-dipole interaction induces logical phase

$$|0\rangle|0\rangle \rightarrow |0\rangle|0\rangle$$

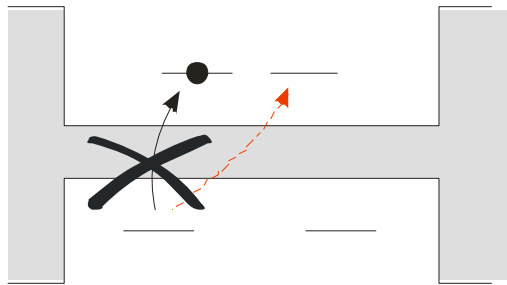
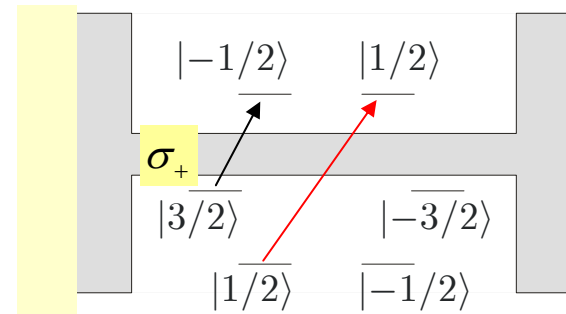
$$|0\rangle|1\rangle \rightarrow |0\rangle|1\rangle$$

$$|1\rangle|0\rangle \rightarrow |1\rangle|0\rangle$$

$$|1\rangle|1\rangle \rightarrow e^{i\Delta E_{ab}t} |1\rangle|1\rangle$$

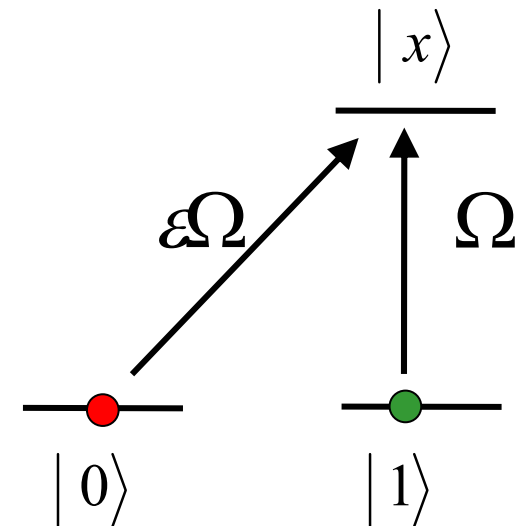
# Hole mixing problem

- Light holes couple to electron  $+1/2$  states via  $\sigma+$  light
- Actual hole eigenstates comprise a certain admixture from light holes



- Pauli blocking does not work perfectly
- A  $\pi + \pi$  pulse for the transition  $|1\rangle - |x\rangle$  will leave behind some excitonic population

- A different gate operation procedure is needed
- Model including hole mixing via effective weak coupling to state  $|0\rangle$
- Typical value for  $\epsilon$ :  $\sim 10\%$

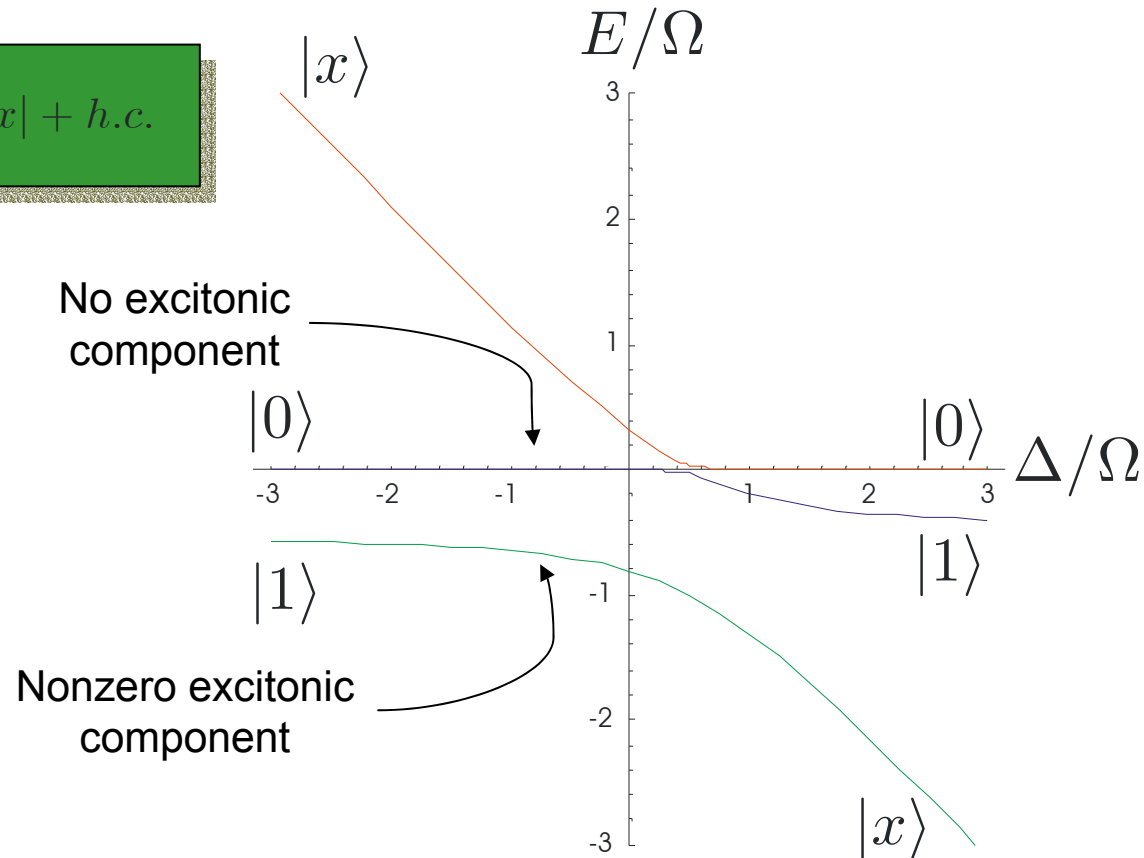




# Hole-mixing tolerant laser excitation

$$H_1 = H_0 + \delta |1\rangle \langle 1| + \frac{\varepsilon \Omega}{2} |0\rangle \langle x| + h.c.$$

- Start far from resonance
- Adiabatically change the detuning towards resonance
- Reach  $|x\rangle$  from  $|1\rangle$  but not from  $|0\rangle$
- Adiabatically de-excite by returning to the initial situation



$$\alpha |0\rangle + \beta |1\rangle \rightarrow \alpha |0\rangle + \beta \left( \cos \frac{\theta}{2} |1\rangle - \sin \frac{\theta}{2} |x\rangle \right)$$

# Adiabatically suppressing decoherence in gate operation

pulse shapes

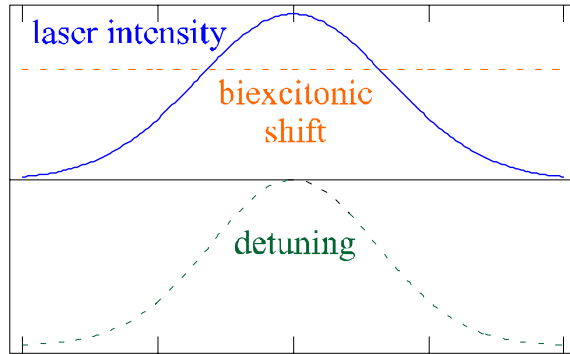
$$\Omega(t) = \Omega_0 e^{-(t/\tau_\Omega)^2}$$

$$\Delta(t) = \Delta_\infty \left[ 1 - e^{-(t/\tau_\Delta)^2} \right]$$

coupling to phonons  
induces dephasing:  
spin-phonon model

$$\sum \lambda_{j\mathbf{q}} (b_{j\mathbf{q}} + b_{j\mathbf{q}}^\dagger) |x\rangle \langle x| + \omega_j(\mathbf{q}) b_{j\mathbf{q}}^\dagger b_{j\mathbf{q}}$$

$\Omega_0 = 3 \text{ meV}$   
 $\tau_\Omega = 10 \text{ ps}$   
 $\Delta E_{ab} = 2 \text{ meV}$   
 $\delta = 0.5 \text{ meV}$   
 $\Delta_\infty = 3 \text{ meV}$   
 $\tau_\Delta = 8.72 \text{ ps}$



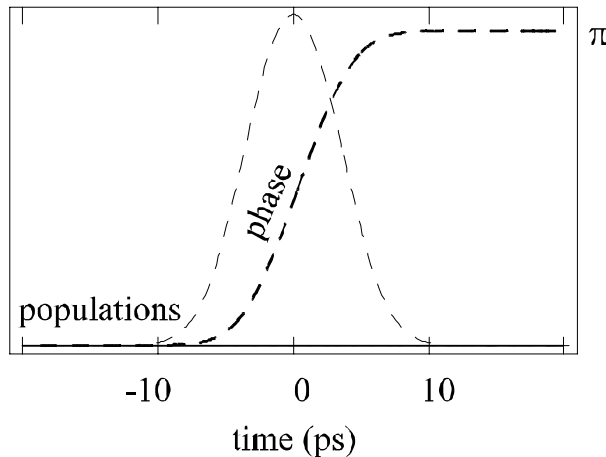
phonon Hamiltonian in dressed-state basis

$$H_{\text{ph}} = \left[ E_+ + \sum_{\mathbf{q}} \omega(\mathbf{q}) b_{\mathbf{q}}^\dagger b_{\mathbf{q}} + \cos^2 \frac{\theta}{2} \lambda_{\mathbf{q}} (b_{\mathbf{q}}^\dagger + b_{\mathbf{q}}) \right] |+\rangle \langle +|$$

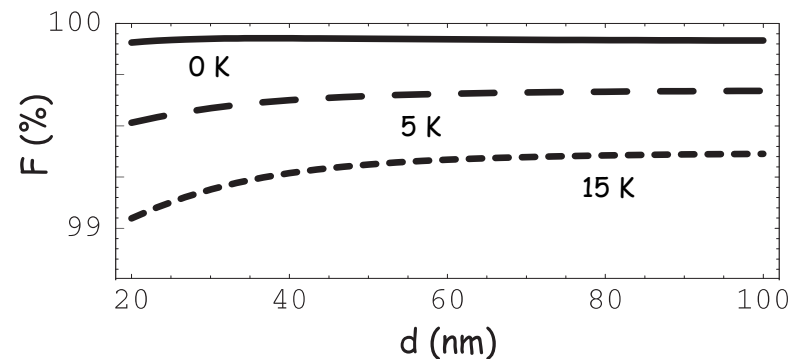
$$+ \left[ E_- + \sum_{\mathbf{q}} \omega(\mathbf{q}) b_{\mathbf{q}}^\dagger b_{\mathbf{q}} - \sin^2 \frac{\theta}{2} \lambda_{\mathbf{q}} (b_{\mathbf{q}}^\dagger + b_{\mathbf{q}}) \right] |-\rangle \langle -|$$

$$- \frac{\sin \theta}{2} \sum \lambda_{\mathbf{q}} (b_{\mathbf{q}}^\dagger + b_{\mathbf{q}}) (|+\rangle \langle -| + |-\rangle \langle +|)$$

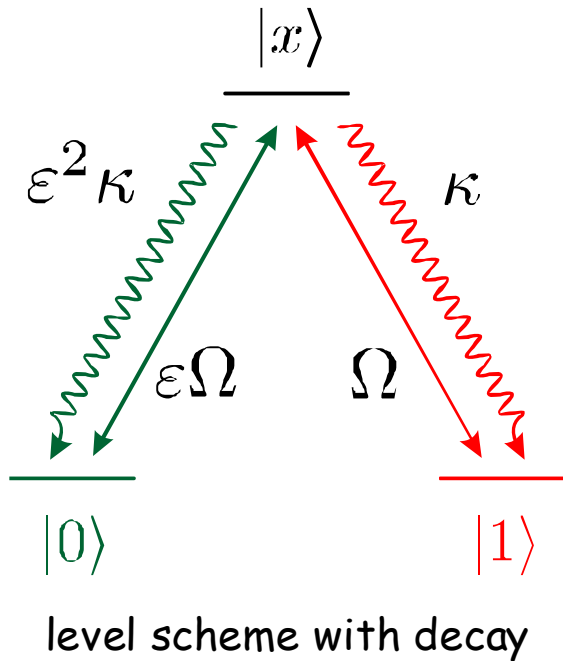
residual population in the unwanted excitonic states is smaller than  $10^{-6}$  after gate operation



- The same procedure avoids the effect of both hole mixing and phonon decoherence

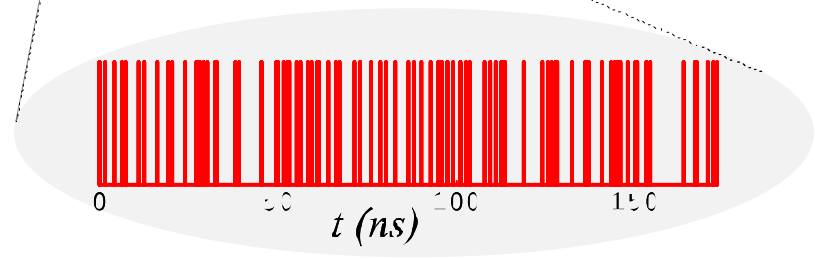
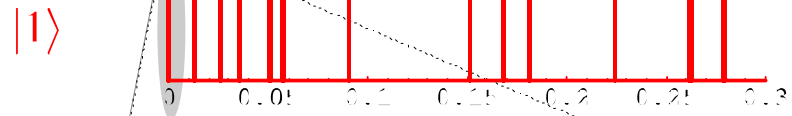
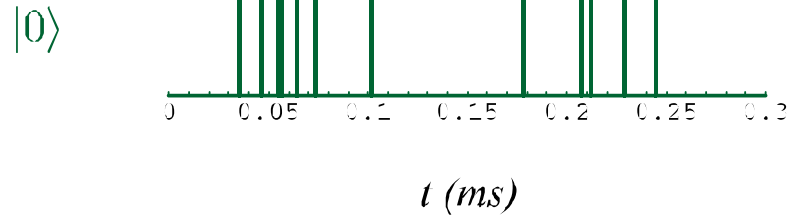


# Qubit read-out



error probability ( $\sim 0.2\%$  with 80% counting efficiency and 10% mixing)

photon count simulation



$$P_\epsilon = \frac{\epsilon^2(1-\eta)}{\epsilon^2 + \eta} \left[ 1 - \left( \frac{1-\eta}{1+\epsilon^2} \right)^{1+\epsilon^{-2}} \right]$$

# Summary

- [Quantum Computing based on] neutral atoms in optical lattices
  - spin-dependent lattices
  - high fidelity loading of large lattice arrays beyond Mott insulator
- Entangling atoms
  - two-atoms Feshbach & photoassociation gates
  - atoms in pipeline structures
- All-optical quantum computing with quantum dots
  - Suppressing decoherence via quantum-optical techniques